

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSIII)

# 2SK2718

DC-DC Converter and Motor Drive Applications

- Low drain-source ON resistance :  $R_{DS(ON)} = 5.6 \Omega$  (typ.)
- High forward transfer admittance :  $|Y_{fs}| = 2.0 \text{ S}$  (typ.)
- Low leakage current :  $I_{DSS} = 100 \mu\text{A}$  (max) ( $V_{DS} = 720 \text{ V}$ )
- Enhancement mode :  $V_{th} = 2.0 \text{ to } 4.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1 \text{ mA}$ )

## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	900	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	900	V
Gate-source voltage		$V_{GSS}$	$\pm 30$	V
Drain current	DC (Note 1)	$I_D$	2.5	A
	Pulse (Note 1)	$I_{DP}$	7.5	A
Drain power dissipation ( $T_c = 25^\circ\text{C}$ )		$P_D$	40	W
Single pulse avalanche energy (Note 2)		$E_{AS}$	216	mJ
Avalanche current		$I_{AR}$	2.5	A
Repetitive avalanche energy (Note 3)		$E_{AR}$	4.0	mJ
Channel temperature		$T_{ch}$	150	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55 to 150	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	3.125	$^\circ\text{C} / \text{W}$
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	62.5	$^\circ\text{C} / \text{W}$

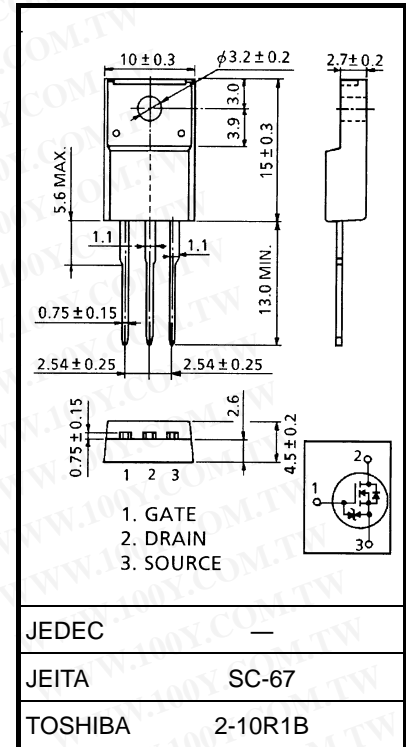
Note 1: Ensure that the channel temperature does not exceed  $150^\circ\text{C}$ .

Note 2:  $V_{DD} = 90 \text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 63.4 \text{ mH}$ ,  $R_G = 25 \Omega$ ,  $I_{AR} = 2.5 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.  
Please handle with caution.

Unit: mm



Weight: 1.9 g (typ.)

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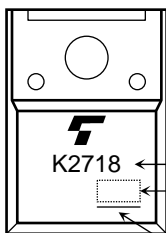
### Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		$I_{GSS}$	$V_{GS} = \pm 25\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Gate-source breakdown voltage		$V_{(BR)GSS}$	$I_G = \pm 10\ \mu\text{A}, V_{DS} = 0\text{ V}$	$\pm 30$	—	—	V
Drain cut-off current		$I_{DSS}$	$V_{DS} = 720\text{ V}, V_{GS} = 0\text{ V}$	—	—	100	$\mu\text{A}$
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	900	—	—	V
Gate threshold voltage		$V_{th}$	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	2.0	—	4.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 1.5\text{ A}$	—	5.6	6.4	$\Omega$
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 20\text{ V}, I_D = 1.5\text{ A}$	1.0	2.0	—	S
Input capacitance		$C_{iss}$	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	510	—	pF
Reverse transfer capacitance		$C_{rss}$		—	10	—	
Output capacitance		$C_{oss}$		—	55	—	
Switching time	Rise time	$t_r$		—	20	—	ns
	Turn-on time	$t_{on}$		—	60	—	
	Fall time	$t_f$		—	40	—	
	Turn-off time	$t_{off}$		—	115	—	
Total gate charge (gate-source plus gate-drain)		$Q_g$	$V_{DD} \approx 400\text{ V}, V_{GS} = 10\text{ V}, I_D = 2.5\text{ A}$	—	21	—	nC
Gate-source charge		$Q_{gs}$		—	11	—	
Gate-drain ("miller") Charge		$Q_{gd}$		—	10	—	

### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	$I_{DR}$	—	—	—	2.5	A
Pulse drain reverse current (Note 1)	$I_{DRP}$	—	—	—	7.5	A
Forward voltage (diode)	$V_{DSF}$	$I_{DR} = 2.5\text{ A}, V_{GS} = 0\text{ V}$	—	—	-2.0	V
Reverse recovery time	$t_{rr}$	$I_{DR} = 2.5\text{ A}, V_{GS} = 0\text{ V}$	—	960	—	ns
Reverse recovery charge	$Q_{rr}$	$dI_{DR} / dt = 100\text{ A} / \mu\text{s}$	—	5.3	—	$\mu\text{C}$

### Marking



Part No. (or abbreviation code)  
 Lot No.

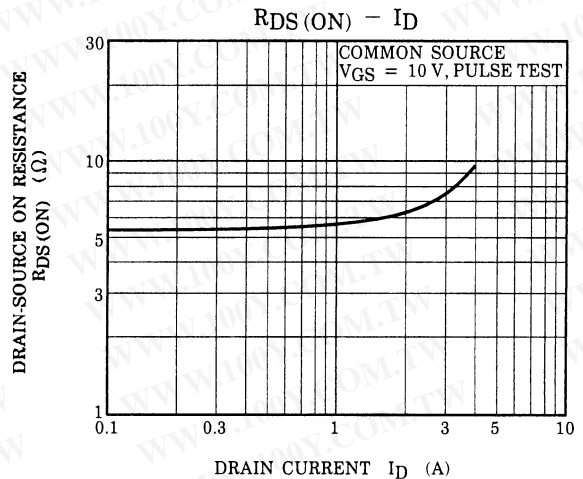
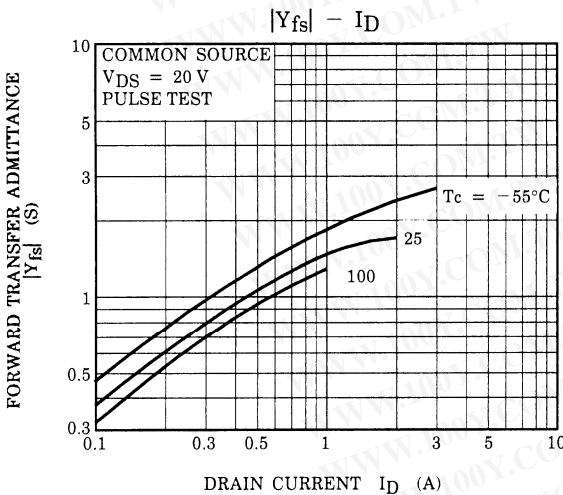
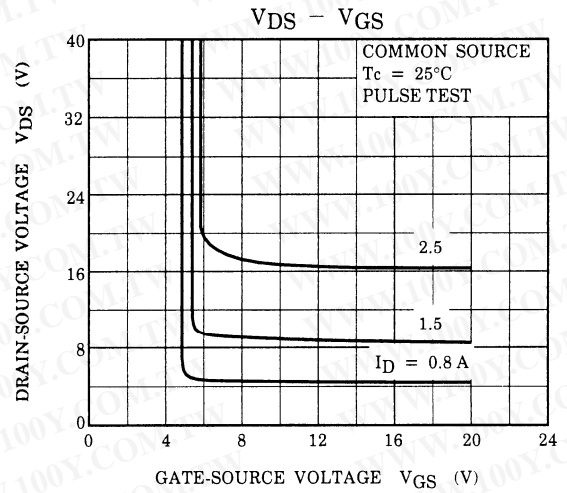
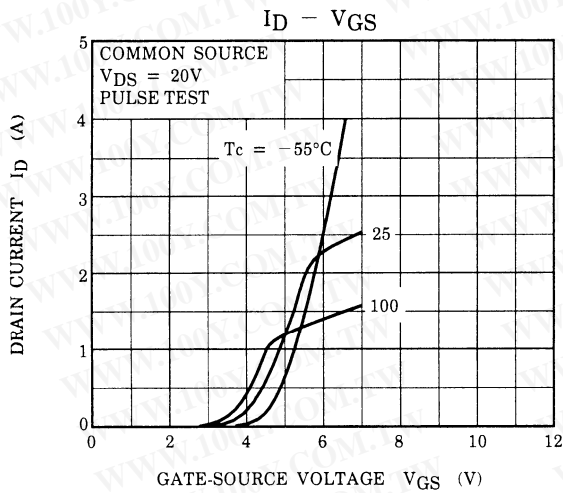
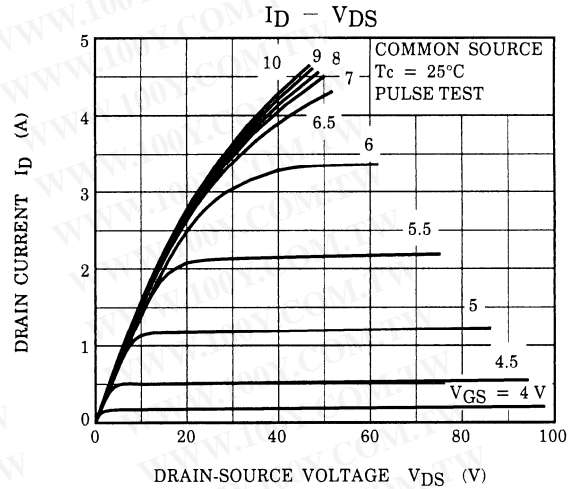
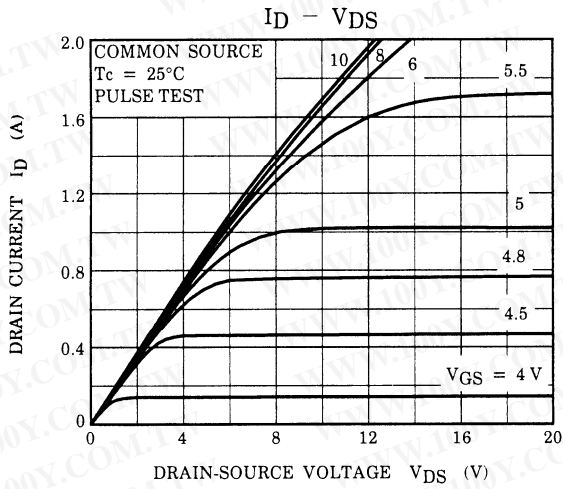
Note 4

Note 4: A line under a Lot No. identifies the indication of product Labels.

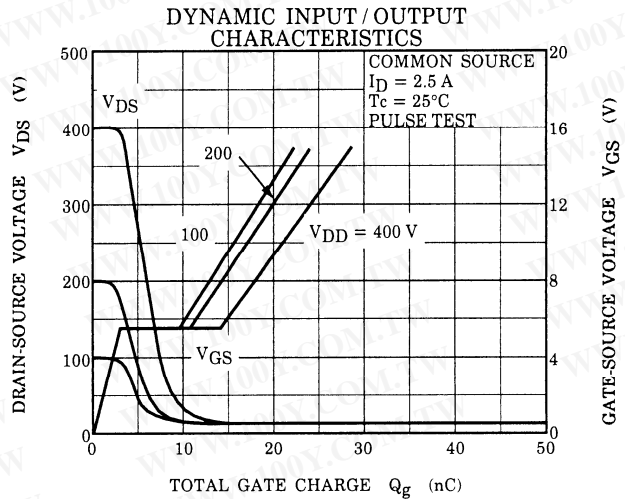
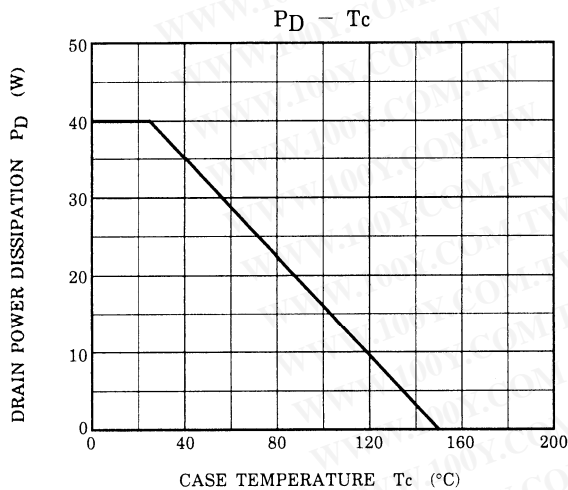
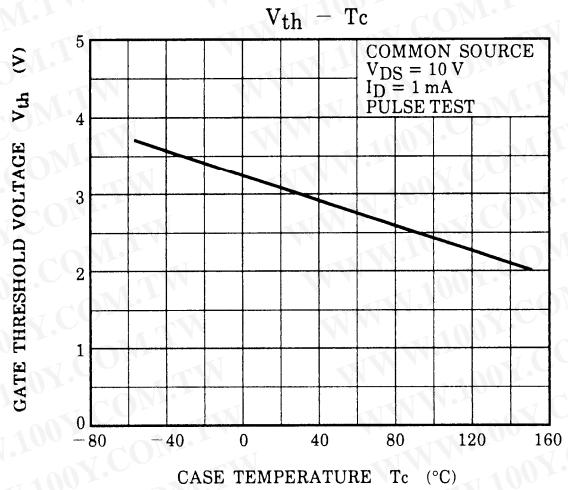
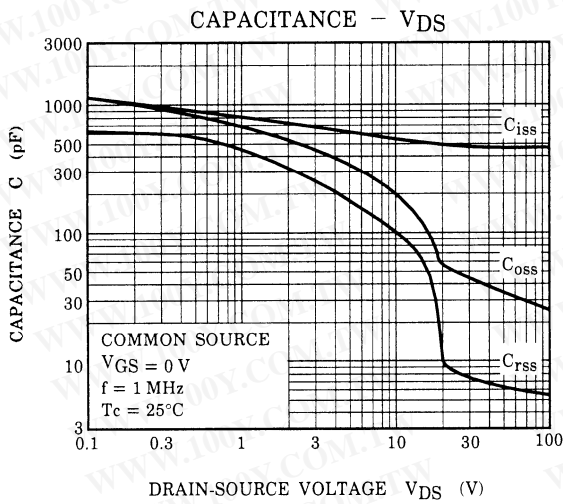
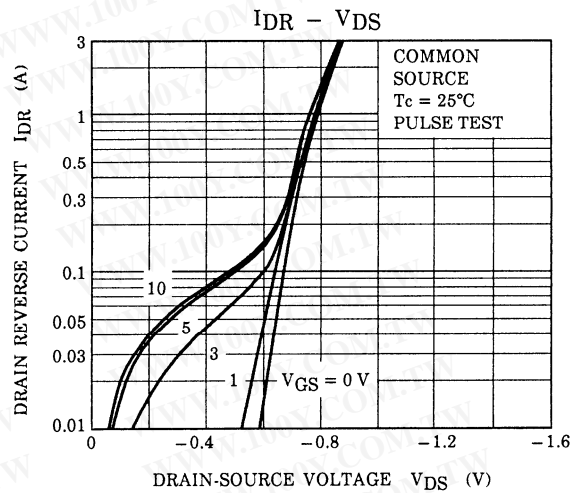
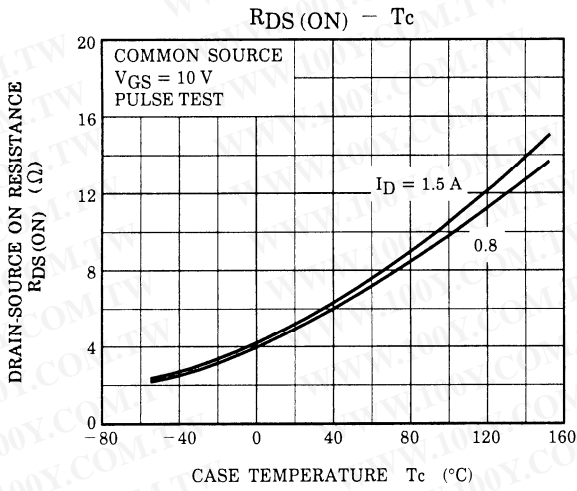
Not underlined:  $[[\text{Pb}]]/\text{INCLUDES} > \text{MCV}$

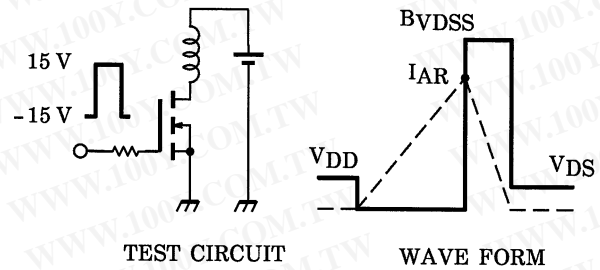
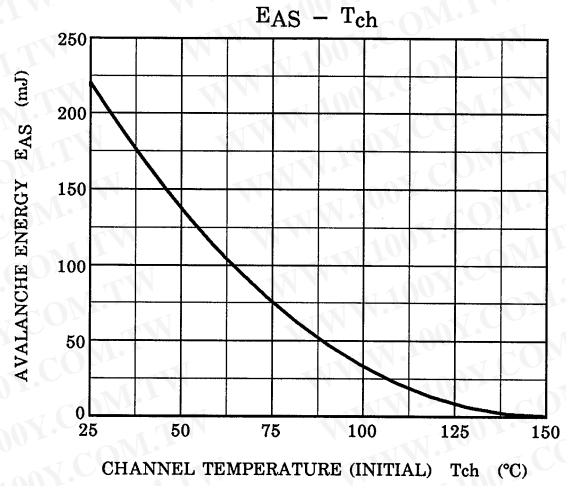
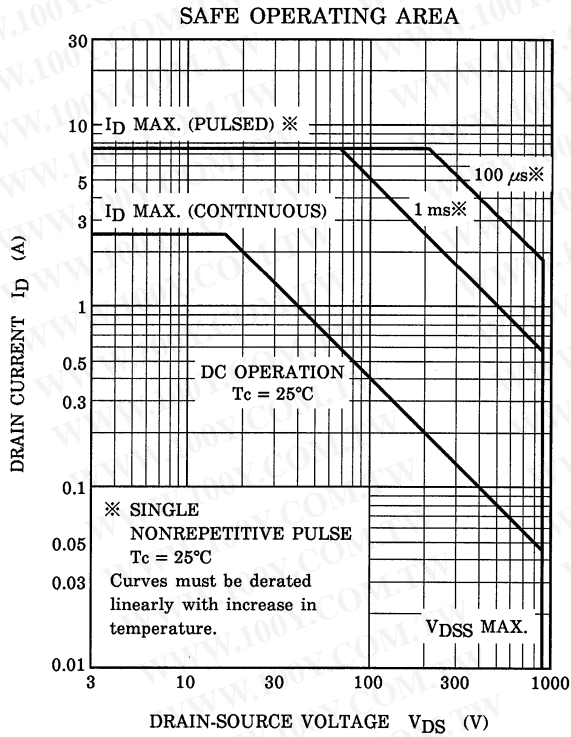
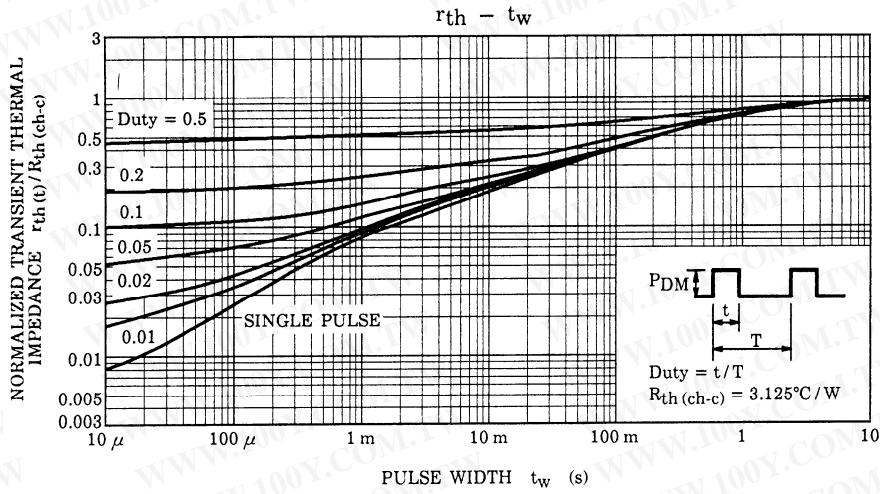
Underlined:  $[[\underline{\text{G}}]]/\text{RoHS COMPATIBLE}$  or  $[[\underline{\text{G}}]]/\text{RoHS} [[\text{Pb}]]$

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$R_G = 25 \Omega$

$V_{DD} = 90 \text{ V}, L = 63.4 \text{ mH}$

$$EAS = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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